NSN 5961-01-077-8571

Semiconductor Device Set - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-077-8571 **Inclosure Material:** Metal all transistor **Overall Length:** 0.805 inches all transistor and 0.925 inches all transistor Overall Width: 1.255 inches all transistor and 1.475 inches all transistor **Mounting Facility Quantity:** 1 all transistor **Internal Configuration:** Junction contact all transistor Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-117 all transistor **Internal Junction Configuration:** Npn all transistor **Component Function Relationship:** Matched **Component Name And Quantity:** 2 transistor **Mounting Method:** Threaded stud all transistor **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches all transistor **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, collector-to-emitter, base open all transistor **Current Rating Per Characteristic:** 4.00 amperes source cutoff current all transistor **Thread Series Designator:** Unc all transistor **Terminal Type And Quantity:** 4 ribbon all transistor Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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